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[Vishay/Siliconix](#)  
[SI7925DN-T1-E3](#)

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**Si7925DN**  
Vishay Siliconix

## Dual P-Channel 12-V (D-S) MOSFET

### PRODUCT SUMMARY

$V_{DS}$ (V)	$R_{DS(on)}$ ( $\Omega$ )	$I_D$ (A)
- 12	0.042 at $V_{GS} = - 4.5$ V	- 6.5
	0.058 at $V_{GS} = - 2.5$ V	- 5.5
	0.082 at $V_{GS} = - 1.8$ V	- 1.2

### FEATURES

- Halogen-free Option Available
- TrenchFET® Power MOSFET: 1.8 V Rated

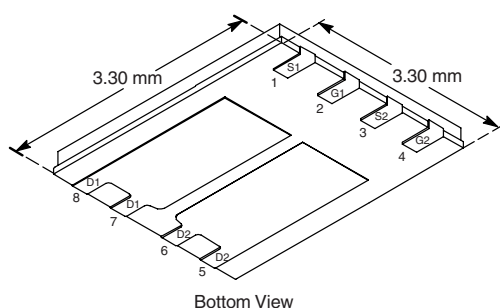
### APPLICATIONS

- Load Switch
- PA Switch
- Battery Switch
- Bi-Directional Switch



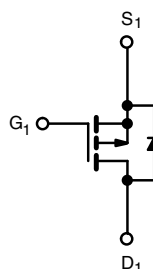
**RoHS**  
COMPLIANT

PowerPAK 1212-8

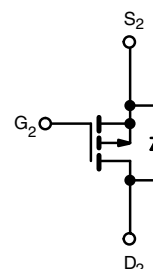


Bottom View

Ordering Information: SI7925DN-T1-E3 (Lead (Pb)-free)  
SI7925DN-T1-GE3 (Lead (Pb)-free and Halogen-free)



P-Channel MOSFET



P-Channel MOSFET

### ABSOLUTE MAXIMUM RATINGS $T_A = 25^\circ\text{C}$ , unless otherwise noted

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)					
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	- 12		V
Gate-Source Voltage		V <sub>GS</sub>	± 8		
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 6.5	- 4.8	A
	T <sub>A</sub> = 85 °C		- 4.7	- 3.4	
Pulsed Drain Current		I <sub>DM</sub>	- 20		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	- 2.1	- 1.1	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.5	1.3	
	T <sub>A</sub> = 85 °C		1.5	0.69	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C
Soldering Recommendations (Peak Temperature) <sup>b, c</sup>			260		

### THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>a</sup>	$R_{thJA}$	40	50	$^\circ\text{C/W}$
		75	94	
Maximum Junction-to-Case	$R_{thJC}$	5.6	7	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<http://www.vishay.com/ppg?73257>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

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<b>SPECIFICATIONS</b> $T_J = 25\text{ }^{\circ}\text{C}$ , unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = -250\text{ }\mu\text{A}$	-0.40		-1.0	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}$ , $V_{GS} = \pm 8\text{ V}$			$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -12\text{ V}$ , $V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
		$V_{DS} = -12\text{ V}$ , $V_{GS} = 0\text{ V}$ , $T_J = 85\text{ }^{\circ}\text{C}$			-5	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}$ , $V_{GS} = -4.5\text{ V}$	-20			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}$ , $I_D = -6.5\text{ A}$		0.033	0.042	$\Omega$
		$V_{GS} = -2.5\text{ V}$ , $I_D = -5.5\text{ A}$		0.046	0.058	
		$V_{GS} = -1.8\text{ V}$ , $I_D = -1.2\text{ A}$		0.065	0.082	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -6\text{ V}$ , $I_D = -6.5\text{ A}$		19		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = -2.1\text{ A}$ , $V_{GS} = 0\text{ V}$		-0.8	-1.2	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$Q_g$	$V_{DS} = -6\text{ V}$ , $V_{GS} = -4.5\text{ V}$ , $I_D = -6.5\text{ A}$		11	12	nC
Gate-Source Charge	$Q_{gs}$			1.7		
Gate-Drain Charge	$Q_{gd}$			2.8		
Gate Resistance	$R_g$			8.2		$\Omega$
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -6\text{ V}$ , $R_L = 6\text{ }\Omega$ $I_D \approx -1\text{ A}$ , $V_{GEN} = -4.5\text{ V}$ , $R_G = 6\text{ }\Omega$		20	30	ns
Rise Time	$t_r$			50	75	
Turn-Off Delay Time	$t_{d(off)}$			70	105	
Fall Time	$t_f$			50	75	
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = -2.1\text{ A}$ , $dI/dt = 100\text{ A}/\mu\text{s}$		41	80	

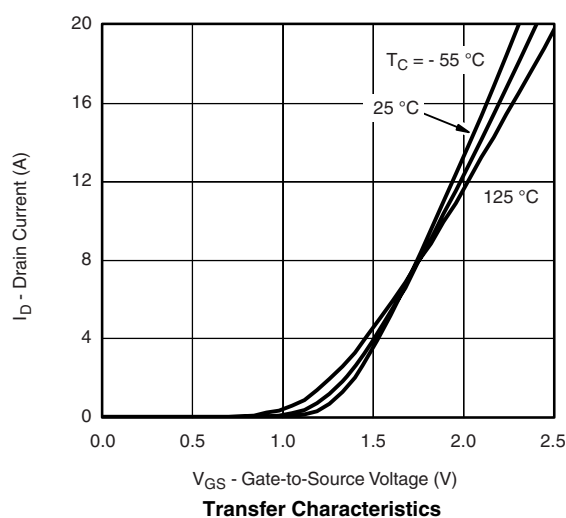
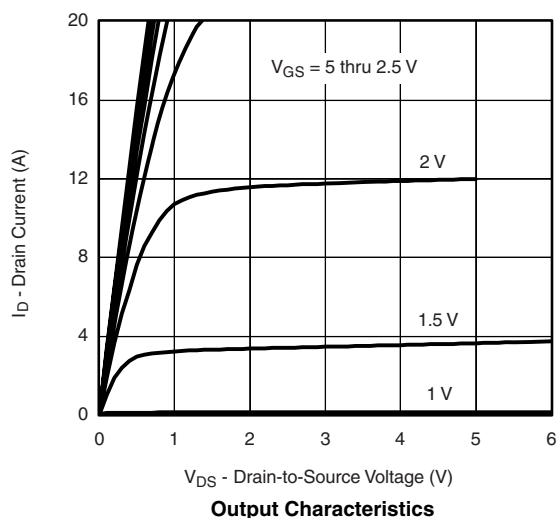
Notes:

a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## TYPICAL CHARACTERISTICS $25\text{ }^{\circ}\text{C}$ , unless otherwise noted

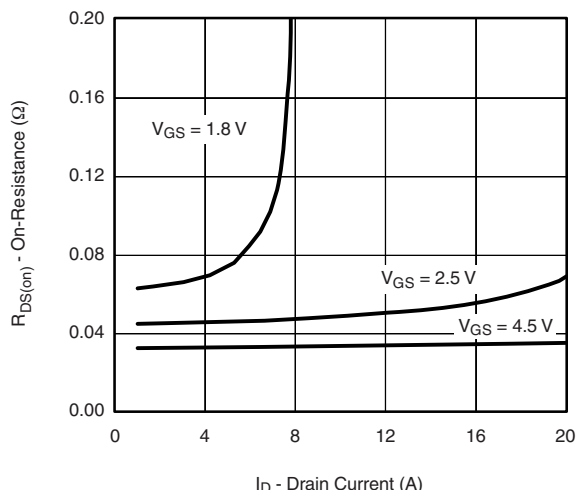




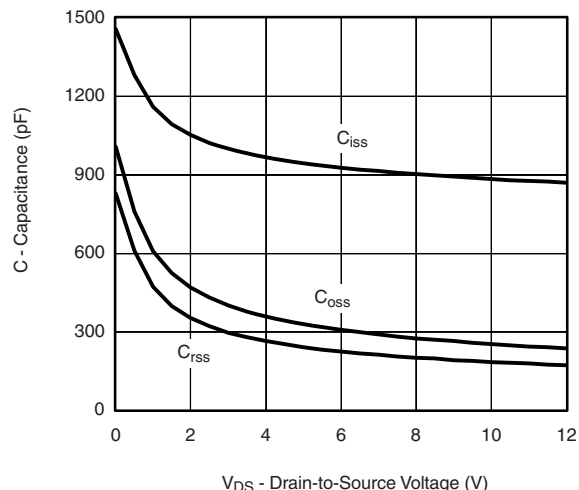
# Si7925DN

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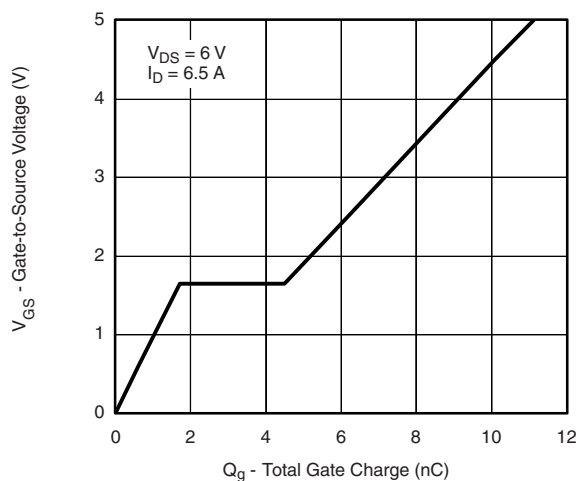
## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



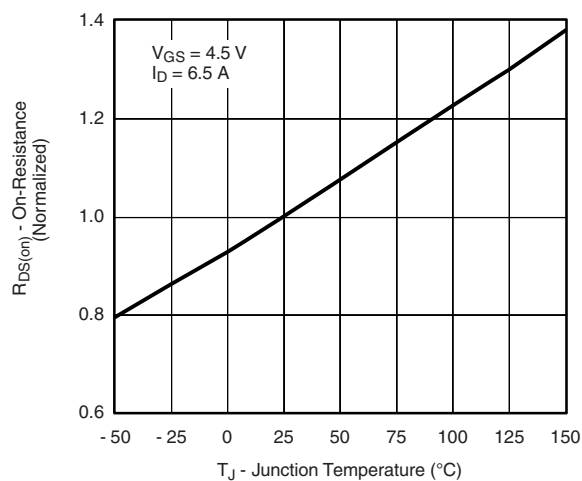
**On-Resistance vs. Drain Current**



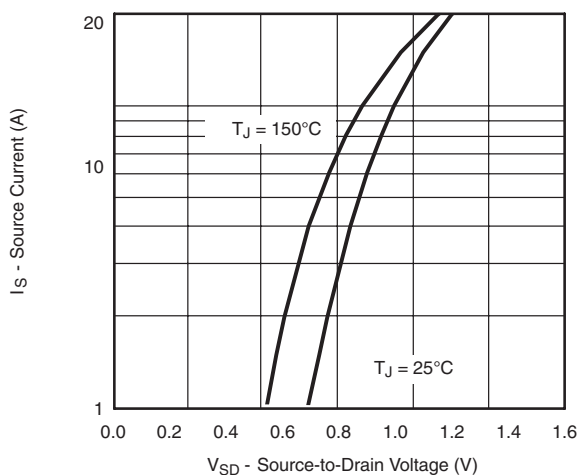
**Capacitance**



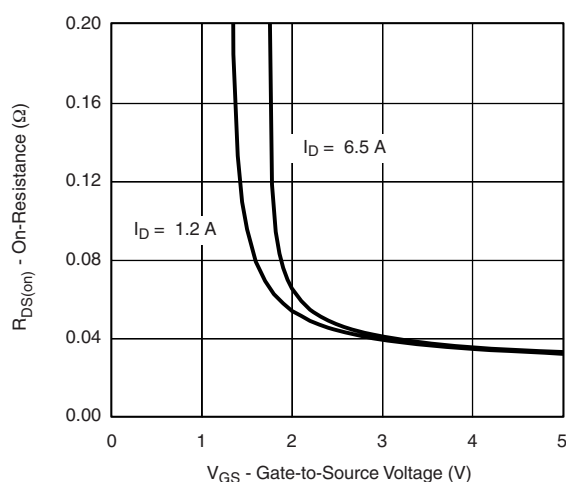
**Gate Charge**



**On-Resistance vs. Junction Temperature**



**Source-Drain Diode Forward Voltage**



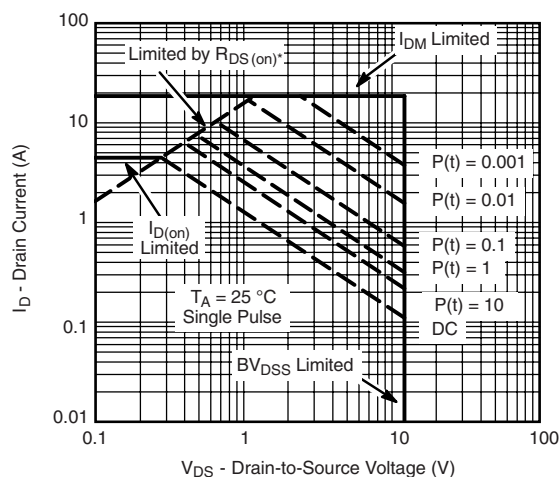
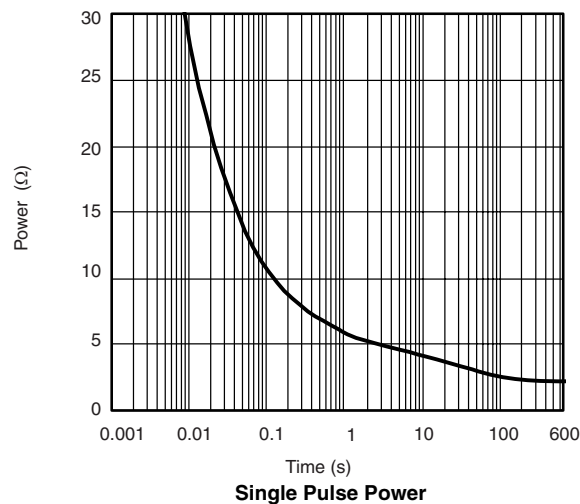
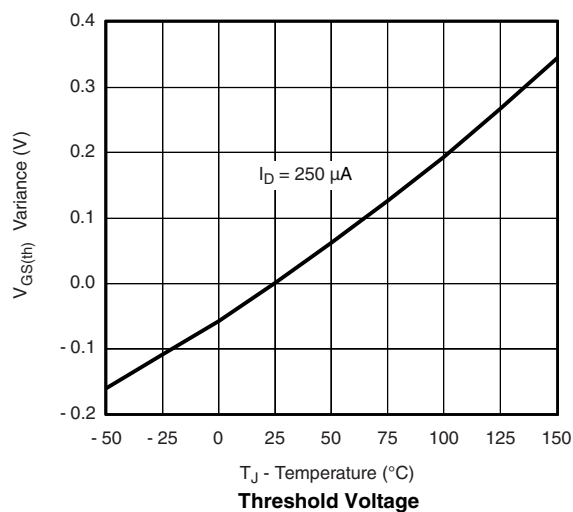
**On-Resistance vs. Gate-to-Source Voltage**

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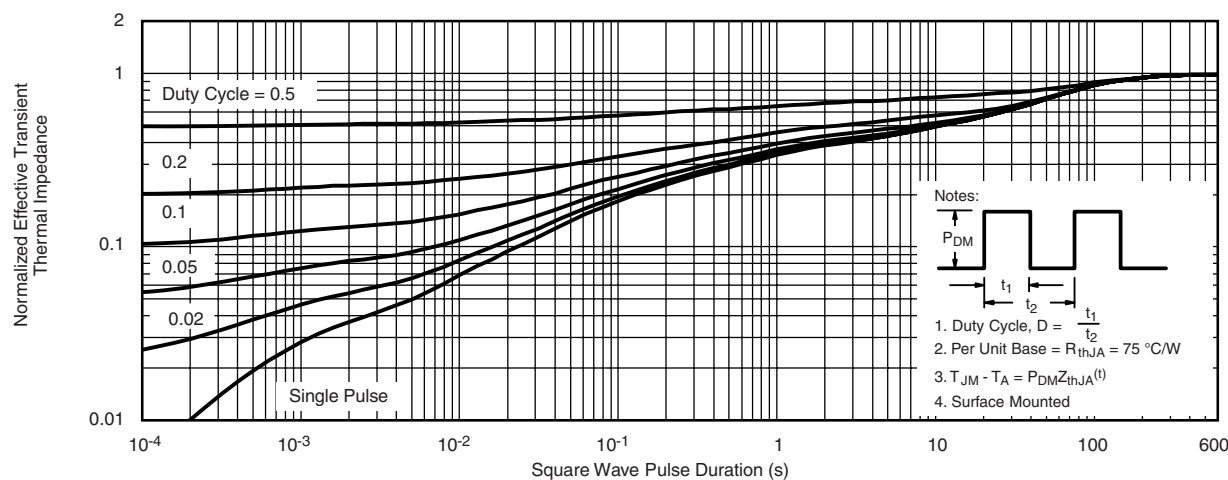


## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



\*  $V_{GS} >$  minimum  $V_{GS}$  at which  $R_{DS(on)}$  is specified

**Safe Operating Area, Junction-to-Ambient**

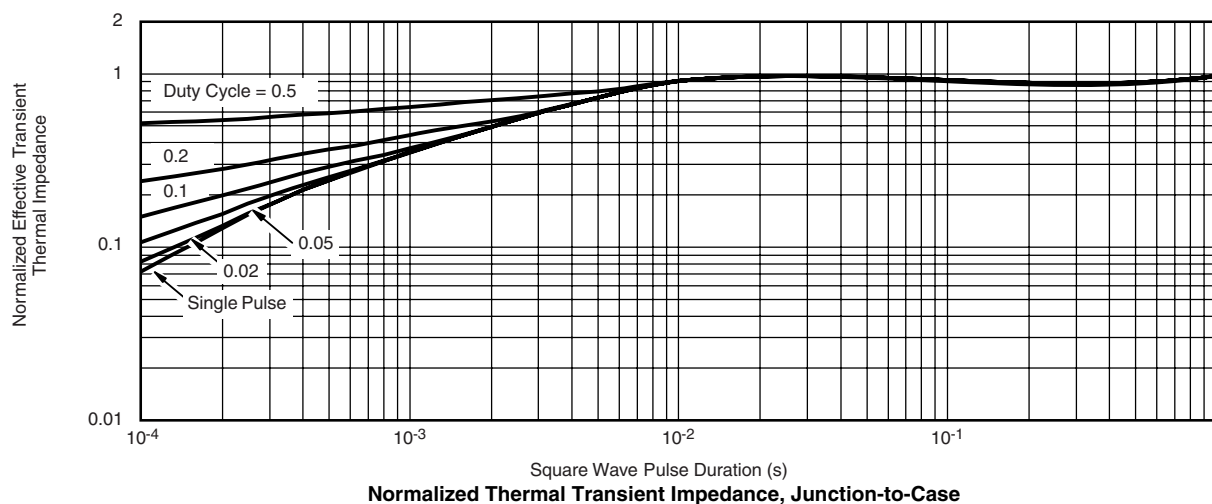




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**TYPICAL CHARACTERISTICS** 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <http://www.vishay.com/ppg?72343>.



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